

# SMS05 THRU SMS24 TVS Diode Array For ESD and Latch-Up Protection

#### PROTECTION PRODUCTS

#### Description

The SMS series of TVS arrays are designed to protect sensitive electronics from damage or latch-up due to ESD and other voltage-induced transient events. Each device will protect up to four lines. They are available with operating voltages of 5V, 12V, 15V and 24V. They are unidirectional devices and may be used on lines where the signal polarities are above ground.

TVS diodes are solid-state devices designed specifically for transient suppression. They feature large cross-sectional area junctions for conducting high transient currents. They offer desirable characteristics for board level protection including fast response time, low operating and clamping voltage and no device degradation.

The SMS series devices may be used to meet the immunity requirements of IEC 61000-4-2, level 4. The low cost SOT23-6L package makes them ideal for use in portable electronics such as cell phones, PDA's, and notebook computers.

#### **Features**

- ◆ Transient protection for data lines to IEC 61000-4-2 (ESD) 15kV (air), 8kV (contact) IEC 61000-4-4 (EFT) 40A (5/50ns) IEC 61000-4-5 (Lightning) 24A (8/20µs)
- Small package for use in portable electronics
- ◆ Protects four I/O lines
- ◆ Working voltages: 5V, 12V, 15V and 24V
- Low leakage current
- Low operating and clamping voltages
- Solid-state silicon avalanche technology

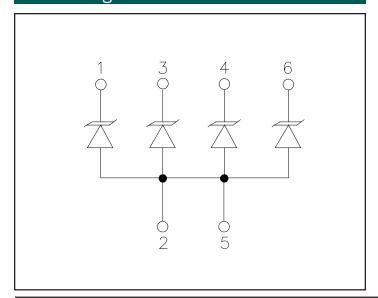
#### **Mechanical Characteristics**

- ◆ EIAJ SOT23-6L package
- Molding compound flammability rating: UL 94V-0
- Marking: Marking Code
- ◆ Packaging: Tape and Reel per EIA 481

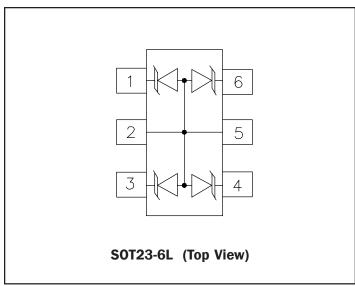
#### **Applications**

- Cell phone Handsets and Accessories
- Microprocessor Based Equipment
- ◆ Personal Digital Assistants (PDA's) and Pagers
- Desktops PC and Servers
- Notebook, Laptop, and Palmtop Computers
- ◆ Portable Instrumentation
- Peripherals
- MP3 Players
- Cordless Phones

#### Circuit Diagram



# Schematic & PIN Configuration





# Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power (tp = 8/20μs)	$P_{pk}$	350	Watts
ESD Voltage (HBM per IEC 61000-4-2)	V <sub>PP</sub>	>25	kV
Lead Soldering Temperature	T <sub>L</sub>	260 (10 sec.)	°C
Operating Temperature	T <sub>J</sub>	-55 to +125	°C
Storage Temperature	T <sub>STG</sub>	-55 to +150	°C

# **Electrical Characteristics**

SMS05						
Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	V <sub>RWM</sub>				5	V
Reverse Breakdown Voltage	V <sub>BR</sub>	I <sub>t</sub> = 1mA	6			V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 5V, T=25°C			20	μΑ
Clamping Voltage	V <sub>c</sub>	$I_{pp} = 5A, t_p = 8/20 \mu s$			9.8	V
Clamping Voltage	V <sub>c</sub>	$I_{pp} = 24A, t_{p} = 8/20\mu s$			14.5	V
Maximum Peak Pulse Current	l <sub>pp</sub>	t <sub>p</sub> = 8/20μs			24	Α
Junction Capacitance	C <sub>j</sub>	Between I/O Pins and Gnd V <sub>R</sub> = OV, f = 1MHz		325	400	pF

SMS12						
Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	V <sub>RWM</sub>				12	V
Reverse Breakdown Voltage	V <sub>BR</sub>	I <sub>t</sub> = 1mA	13.3			V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 12V, T=25°C			1	μΑ
Clamping Voltage	V <sub>c</sub>	$I_{pp} = 5A, t_{p} = 8/20 \mu s$			19	V
Clamping Voltage	V <sub>c</sub>	$I_{pp} = 15A, t_{p} = 8/20\mu s$			23	V
Maximum Peak Pulse Current	I <sub>pp</sub>	t <sub>p</sub> = 8/20µs			15	Α
Junction Capacitance	C <sub>j</sub>	Between I/O Pins and Gnd V <sub>R</sub> = OV, f = 1MHz		135	150	pF



# Electrical Characteristics (Continued)

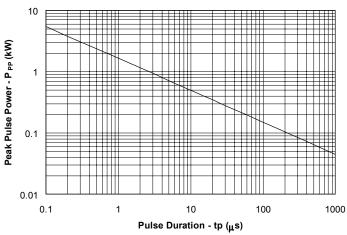
SMS15						
Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	V <sub>RWM</sub>				15	V
Reverse Breakdown Voltage	$V_{_{BR}}$	I <sub>t</sub> = 1mA	16.7			V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 15V, T=25°C			1	μA
Clamping Voltage	V <sub>c</sub>	$I_{pp} = 5A, t_p = 8/20 \mu s$			24	V
Clamping Voltage	V <sub>c</sub>	$I_{pp} = 12A, t_p = 8/20\mu s$			29	V
Maximum Peak Pulse Current	I <sub>pp</sub>	t <sub>p</sub> = 8/20µs			12	А
Junction Capacitance	C <sub>j</sub>	Between I/O Pins and Gnd V <sub>R</sub> = OV, f = 1MHz		100	125	pF

SMS24						
Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	V <sub>RWM</sub>				24	V
Reverse Breakdown Voltage	V <sub>BR</sub>	I <sub>t</sub> = 1mA	26.7			V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 24V, T=25°C			1	μΑ
Clamping Voltage	V <sub>c</sub>	$I_{pp} = 5A, t_p = 8/20 \mu s$			40	V
Clamping Voltage	V <sub>c</sub>	$I_{pp} = 8A, t_p = 8/20 \mu s$			44	V
Maximum Peak Pulse Current	I <sub>pp</sub>	t <sub>p</sub> = 8/20µs			8	А
Junction Capacitance	C <sub>j</sub>	Between I/O Pins and Gnd V <sub>R</sub> = OV, f = 1MHz		60	75	pF

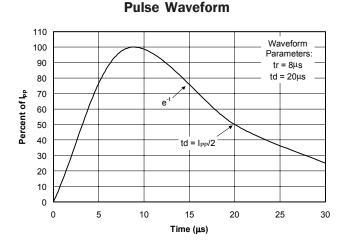


# Typical Characteristics

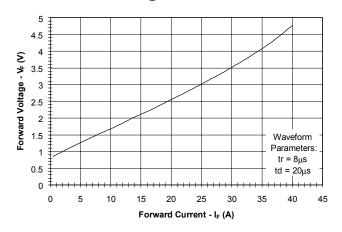
#### Non-Repetitive Peak Pulse Power vs. Pulse Time



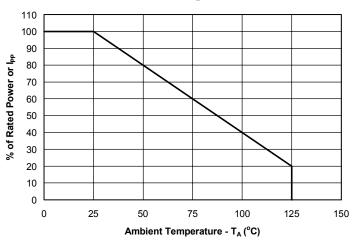
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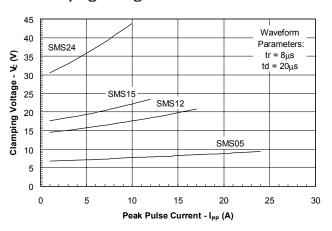
#### Forward Voltage vs. Forward Current



#### **Power Derating Curve**



#### Clamping Voltage vs. Peak Pulse Current





#### **Applications Information**

#### **Device Connection for Protection of Four Data Lines**

The SMSxx is designed to protect up to four unidirectional data lines. The device is connected as follows:

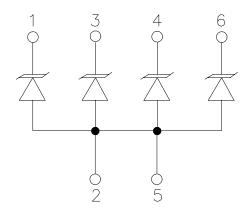
 Unidirectional protection of four I/O lines is achieved by connecting pins 1, 3, 4 and 6 to the data lines. Pin 2 and 5 are connected to ground. The ground connections should be made directly to the ground plane for best results. The path length is kept as short as possible to reduce the effects of parasitic inductance in the board traces.

# Circuit Board Layout Recommendations for Suppression of ESD

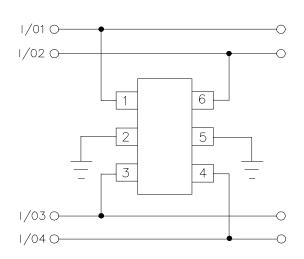
Good circuit board layout is critical for the suppression of ESD induced transients. The following guidelines are recommended:

- Place the SMSxx near the input terminals or connectors to restrict transient coupling.
- Minimize the path length between the SMSxx and the protected line.
- Minimize all conductive loops including power and ground loops.
- The ESD transient return path to ground should be kept as short as possible.
- Never run critical signals near board edges.
- Use ground planes whenever possible.

#### **SMSxx Circuit Diagram**

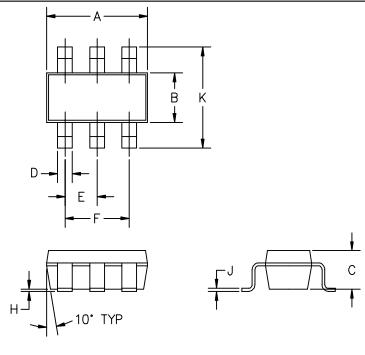


#### **Protection of Four Unidirectional Lines**





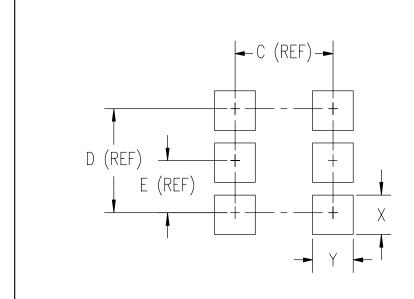
# Outline Drawing



	DIMENSIONS (1)						
DIM	INC	HES	М	NOTE			
ייואווט	MIN	MAX	MIN	MAX	NOIL		
Α	.110	.120	2.80	3.05	_		
В	.059	.070	1.50	1.75	_		
С	.036	.051	.90	1.30	_		
D	.014	.020	.35	.50	-		
E	.033	.040	.85	1.05	-		
F	.067	.083	1.7	2.1	-		
Н	.0004	.006	.010	.150	_		
J	.0035	.008	.090	.20	_		
K	.102	.118	2.6	3.00	_		

- 2 PACKAGE OUTLINE EXCLUSIVE OF MOLD FLASH AND METAL BURR.
- CONTROLLING DIMENSIONS: MILLIMETERS.

# Land Pattern



	DIMENSIONS						
DIM	INCHES	MM	NOTE				
С	.094	2.4	_				
D	.074	1.9	_				
E	.037	.95	_				
Χ	.028	.7					
Y	.039	1.0	_				



# Marking Codes

Part Number	Marking Code
SMS05	05/90
SMS12	12/71
SMS15	15/GL
SMS24	24/77

# Ordering Information

Part Number	Working Voltage	Qty per Reel	Reel Size
SMS05.TC	5V	3,000	7 Inch
SMS05.TG	5V	10,000	13 Inch
SMS12.TC	12V	3,000	7 Inch
SMS12.TG	12V	10,000	13 Inch
SMS15.TC	15V	3,000	7 Inch
SMS15.TG	15V	10,000	13 Inch
SMS24.TC	24V	3,000	7 Inch
SMS24.TG	24V	10,000	13 Inch

Note:

(1) No suffix indicates tube pack.

# Contact Information

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